

**ML7xx16 SERIES**

2.5Gbps InGaAsP DFB LASER DIODE

TYPE  
NAME**ML725B16F****DESCRIPTION**

ML7xx16 series are uncooled DFB (Distributed Feedback) laser diodes for 2.5Gbps transmission emitting light beam at 1310nm.  $\lambda/4$  shifted grating structure is employed to obtain excellent SMSR performance under 2.5Gbps modulation. Furthermore, ML7xx16 can operate in the wide temperature range from -20°C to 85°C without any temperature control.

**FEATURES**

- $\lambda/4$  phase shifted grating structure
- Wide temperature range operation (-20°C to 85°C )
- High side-mode-suppression-ratio (typical 45dB)
- High resonance frequency (typical 11GHz)

**APPLICATION**

2.5Gbps transmission

**ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter	Conditions	Ratings	Unit
Po	Output power	CW	<b>6</b>	mW
IF	Laser forward current	-	<b>200</b>	mA
VRL	Laser reverse voltage	-	<b>2</b>	V
IRD	PD forward current	-	<b>2</b>	mA
VRD	PD reverse voltage	-	<b>20</b>	V
Tc	Operation temperature	-	<b>-20 ~ +85</b>	°C
Tstg	Storage temperature	-	<b>-40 ~ +100</b>	°C

**ELECTRICAL/OPTICAL CHARACTERISTICS (Tc=25°C)**

Symbol	Parameter	Conditions	Limits			Unit
			Min.	Typ.	Max.	
Ith	Threshold current	CW	-	<b>10</b>	<b>15</b>	mA
		CW,Tc=85°C	-	<b>35</b>	<b>50</b>	mA
Iop	Operation current	CW,Po=5mW	-	<b>30</b>	<b>40</b>	mA
		CW,Po=5mW,Tc=85°C	-	<b>75</b>	<b>100</b>	mA
Vop	Operating voltage	CW,Po=5mW	-	<b>1.1</b>	<b>1.8</b>	V
$\eta$	Slope efficiency	CW,Po=5mW	<b>0.18</b>	<b>0.25</b>	-	mW/mA
$\lambda_p$	Peak wavelength	CW,Po=5mW,Tc=-20°C~+85°C	<b>1290</b>	<b>1310</b>	<b>1330</b>	nm
SMSR	Side mode suppression ratio	CW,Po=5mW,Tc=-20°C~+85°C	<b>35</b>	<b>45</b>	-	dB
$\theta_{\parallel}$	Beam divergence angle (parallel)	CW,Po=5mW	-	<b>25</b>	<b>40</b>	deg.
$\theta_{\perp}$	(perpendicular)	CW,Po=5mW	-	<b>30</b>	<b>47</b>	deg.
fr	Resonance frequency	2.48832Gbps, Ibias=Ith,Ipp=40mA	-	<b>11</b>	-	GHz
tr,tf	Rise and fall time(10%-90%)	2.48832Gbps, Ibias=Ith,Ipp=40mA not including package	-	<b>100</b>	<b>150</b>	psec
Im	Monitoring current (PD)	CW,Po=5mW,VRD=1V	<b>0.1</b>	-	<b>2.0</b>	mA
Id	Dark current (PD)	VRD=5V	-	-	<b>1.0</b>	A
Ct	Capacitance (PD)	VRD=5V,f=1MHz	-	<b>10</b>	<b>20</b>	pF

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## OUTLINE DRAWINGS

